NSN 5961-01-258-3484

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-258-3484 **Inclosure Material:** Plastic **Overall Length:** 0.927 inches **Terminal Length:** 0.140 inches **Overall Height:** 0.140 inches **Overall Width:** 0.310 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: T00-91 **Response Time:** 1000.0 nanoseconds all transistor **Component Name And Quantity:** 8 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 50.0 collector to emitter voltage, dc all transistor **Current Rating Per Characteristic:** 600.00 milliamperes forward current, total rms megawatts all transistor **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector absolute all transistor **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 18 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

A110a0